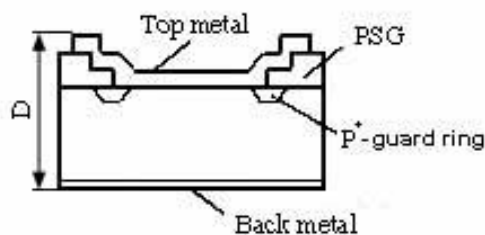
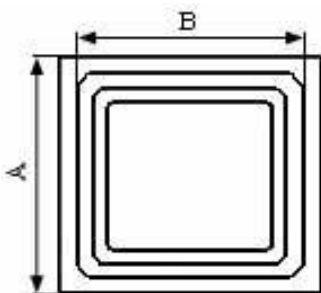




15A/45V. Die Size-115mil.

Electrical Characteristics	Symbol	Unit	Spec. limit	Die Sort
Breakdown Voltage @ $I_R=10\text{mA}$	$V_{BR}$	V	45	50
Average Rectified Forward Current	$I_{F(AV)}$	A	15,0	-
DC Forward Voltage @ 25°C, $I_F=10,0\text{A}$ @ 25°C, $I_F=15,0\text{A}$	$V_F$	V	0,49 0,54	0,47 0,52
Maximum Reverse Current @ 25°C, $V_R=50\text{V}$ @ 25°C, $V_R=45\text{V}$ @ 125°C, $V_R=45\text{V}$	$I_R$	mA	- 0,140 75,0	0,140 0,120 70,0
Peak Forward Surge Current 8,3ms single half sine-wave superimposed on rated load (JEDEC METHOD)	$I_{FSM}$	A	200	-
Peak Repetitive Reverse Surge Current @ 2,0µs, f=1kHz., $T_J<150^\circ\text{C}$ .	$I_{RRM}$	A	4,5	
Electrostatic Discharge Voltage. JEDEC Method. ESD HBM. Contact.	ESD	kV	±8 (contact)	
Voltage Rate of Change	dV/dt	V/µS	10.000	
Operating Junction Temperature	$T_J$	°C	150	



DIM	ITEM	µm
$A_x$ $A_y$	Wafer Form Die Size	2920
$B_x$ $B_y$	Top Metal Size	2780
D	Thickness	300max.
Scribe line Width		80

Top metal:

- a) **Al** – for Wire Bonding;
- b) **Al-Ni-Ag** – for Soldering.

Backside metal: **Ti-Ni-Ag**.